

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. <b>239515US2</b>		SERIAL NO. <b>NEW APPLICATION</b>	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT <b>Keisuke YONEHAMA, et al.</b>			
				FILING DATE <b>HEREWITH</b>		GROUP	
<b>U.S. PATENT DOCUMENTS</b>							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
<b>OK</b>	AA	5,659,500	8/19/97	Freidoon MEHRAD			
<b>OK</b>	AB	6,451,642 B1	9/17/02	Freidoon MEHRAD, et al.			
	AC						
	AD						
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	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
<b>FOREIGN PATENT DOCUMENTS</b>							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION		
					YES	NO	
<b>OK</b>	AO	10-326896	12/8/98	Japan (with English Abstract)		x	
<b>OK</b>	AP	11-265947	9/28/99	Japan (with English Abstract)		x	
<b>OK</b>	AQ	6-334156	12/2/94	Japan (with English Abstract)		x	
<b>OK</b>	AR	2002-76147	3/15/02	Japan (with English Abstract)		x	
<b>OK</b>	AS	7-74326	3/17/95	Japan (with English Abstract)		x	
<b>OK</b>	AT	9-129854	5/16/97	Japan (Corresponds to US 5,659,500)		x	
<b>OK</b>	AU	2001-68571	3/16/01	Japan (Corresponds to US 6,451,642 B1)		x	
	AV						
<b>OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)</b>							
<b>OK</b>	AW	H. WATANABE, et al. "NOVEL 0.44 $\mu$ m <sup>2</sup> TI-SALICIDE STI CELL TECHNOLOGY FOR HIGH-DENSITY NOR FLASH MEMORIES AND HIGH PERFORMANCE EMBEDDED APPLICATION," IEDM 98-975.					
	AX						
	AY						
	AZ					<input type="checkbox"/> Additional References sheet(s) attached	
Examiner <b>Douglas E. Owens</b>					Date Considered <b>9/3/04</b>		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							